Analog & Digital Electronics Course No: PH-218

Lec-20: Power amplifiers and Output Stages

Course Instructor:

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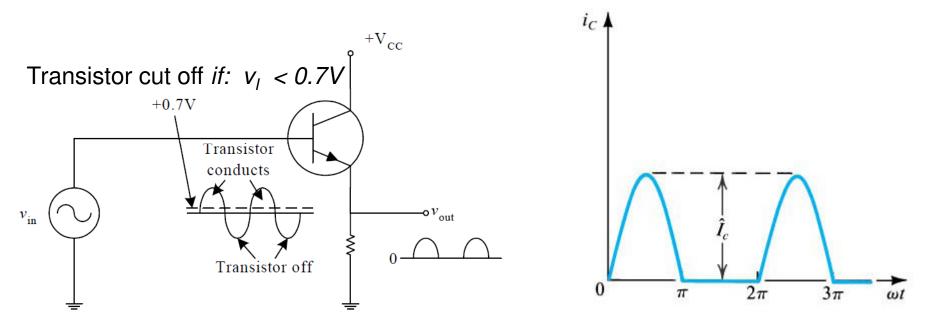


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Class B Power amplifier

> If the collector current flows during the half cycle of the signal only, the power amplifier is known as class B amplifier.

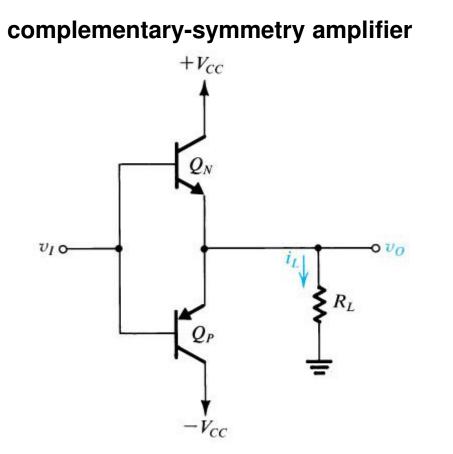
> To have this kind of operation, Q point must be located at cut-off. At cut-off point $I_{CQ} = 0$ and $V_{CEQ} = V_{CE-off}$



The advantage of a class-B amplifier is that the collector current is zero when the input signal to the amplifier is zero.
Therefore the transistor dissipate no power in the quiescent condition.

Class B Push-Pull amplifier

A 2nd class B BJT is needed to conduct for the negative v_l cycle.



vol

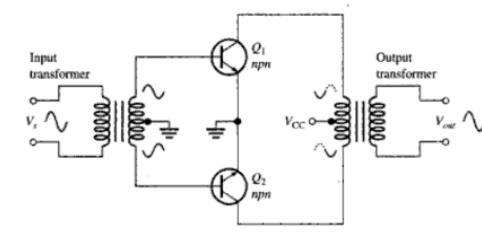
vol

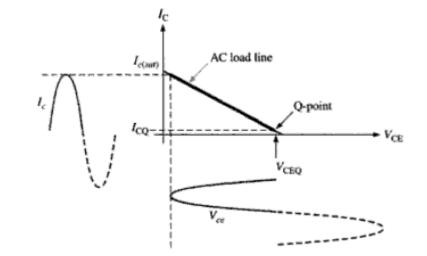
Complementary transistors means one of the transistors is a *npn and the other is pnp.* **Need dual-polarity power supplies.**

Class B Crossover Distortion

Crossover distortion in audio power amps produces unpleasant sounds.

Efficiency: Push Pull Class B Power amplifier





$$P_i(dc) = V_{CC}I_{DC} = \frac{V_{CC}I_C}{\pi} \qquad P_o(ac) = V_{ce} \times I_{ce}$$

$$V_{ce} = \frac{V_{ce-p}}{\sqrt{2}} = \frac{V_{CC}}{2\sqrt{2}} \qquad I_{ce} = \frac{I_{ce-p}}{\sqrt{2}} = \frac{I_C}{\sqrt{2}}$$

$$\eta = \frac{P_o(ac)}{P_i(dc)} \times 100\% \qquad \qquad \eta = \frac{V_{ce} \times I_{ce}}{V_{cc} \times I_{cQ}} \times 100\% = 0.25\pi\% = 78.5\%$$

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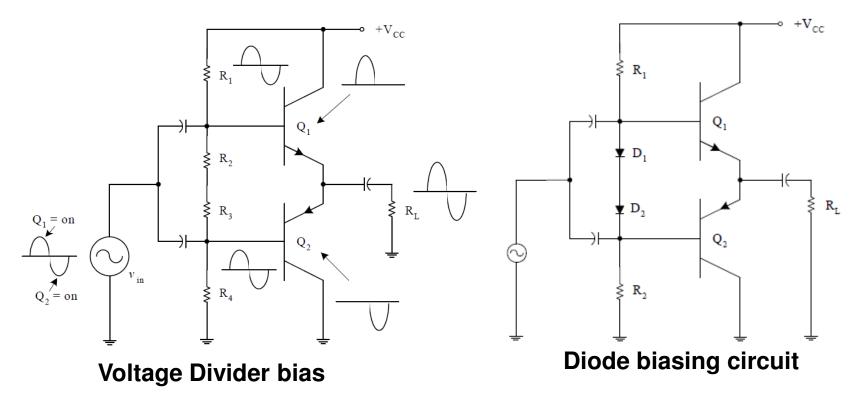
Class B Crossover Distortion V_{BE} $-V_{BE}$ Q_1 conducting Q_2 off Both Q_1 and Q_2 off (crossover distortion) Q_1 off Q_2 conducting

Crossover distortion in audio power amplifers produces unpleasant sounds.

To prevent crossover distortion, both transistors will normally be biased at a level that is slightly *above cutoff.*

Class AB power amplifier

To eliminate crossover distortion, both transistors in the push-pull arrangement must be biased slightly above cut-off when there is no signal.



In voltage divider bias circuit difficult to maintain a stable bias point due to changes in V_{BE} over **temperature changes. (i.e.** $\Delta temp \rightarrow \Delta Q$ -point)

When the diode characteristics of **D1 and D2 are closely matched to the** transconductance characteristics of the transistors, a stable bias can be maintained over temperature.

Amplifier Distortion

> If the output of an amplifier is not a complete AC sine wave, then it is distorting the output. The amplifier is non-linear.

This distortion can be analyzed using Fourier analysis. In Fourier analysis, any distorted periodic waveform can be broken down into frequency components. These components are harmonics of the fundamental frequency.

Harmonics are integer multiples of a fundamental frequency. If the fundamental frequency is F kHz:
 1st harmonic 1 x F kHz
 2nd harmonic 2 x F kHz
 3rd harmonic 3 x F kHz
 4th harmonic 4 x F kHz

Note that the 1st and 3rd harmonics are called odd harmonics and the 2nd and 4th are called even harmonics.

Harmonic Distortion Calculations

Harmonic distortion (D) can be calculated:

% nth harmonic distortion = %D_n =
$$\frac{|A_n|}{|A_1|} \times 100$$

Where A_1 is the amplitude of the fundamental frequency A_n is the amplitude of the highest harmonic.

The total harmonic distortion (THD) is determined by:

% THD = $\sqrt{D_2^2 + D_3^2 + D_3^2 + \cdots} \times 100$

Power Transistor Heat Sinking

Power transistor can dissipate many watts.

All power devices are packaged in cases that permit contact between a metal surface and an external heat sink.

In most cases that metal surface of device is electrically connected to one terminal (e.g. for power transistors the case is always connected to the collector).

heat sink :- provides additional surface area to conduct heat away from the transistors more quickly to prevent overheating.

The whole point of heat sinking is to keep the transistor junction below some maximum specified operating temperature.

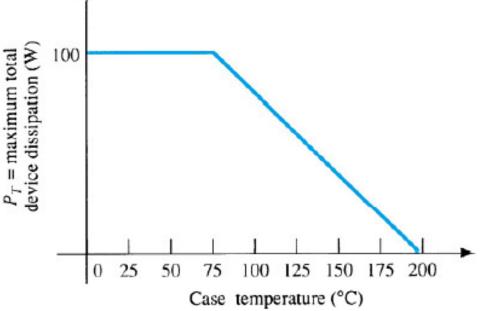
For Si transistors in metal packages the maximum junction temperature is usually 200°C, whereas for transistors in plastic packages it is usually 150°C.

Power Transistor derating curve

$$P_D(T_1) = P_D(T_0) - \kappa(T_1 - T_0)$$

Where

 $P_D(T_0) = Max$ dissipated power at T_0 $P_D(T_1) = Max$ dissipated power at T_1 $T_0 = temp$ at which derating starts $T_1 = Temp$ of interest K = derating factor (W /°C)



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Power Transistor Thermal analogy

$$P_{total} = \frac{T_{j,\max} - T_{amb}}{\theta} \qquad \theta = \theta_{jc} + \theta_{cs} + \theta_{sa}$$

P_{total} = total dissipated power in the transistor ; T_{i-max} = Max junction temperature ;

 T_{amb} = ambient temp ; Θ = total thermal resistance

 θ_{jc} = junction to case thermal resistance ; θ_{cs} = case to heat sink thermal resist

$$\theta_{sa}$$
 = sink to ambient thermal resistance

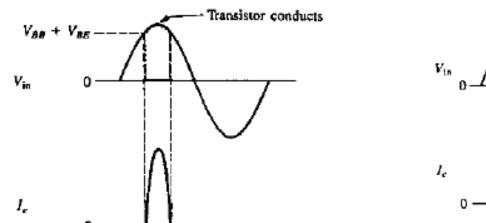
Class C power amplifier

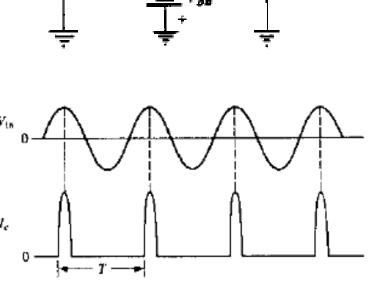
Class C amplifiers are used extensively in radio communications circuits.

 Y_{in} (



The transistor is biased with a negative V_{BE} Thus it will conduct only when the input signal is above a specified positive value. **i.e. transistor 'ON' when V_{in} > V_{BB} + V_{BE}**





 $+V_{CC}$

 $\geq R_C$

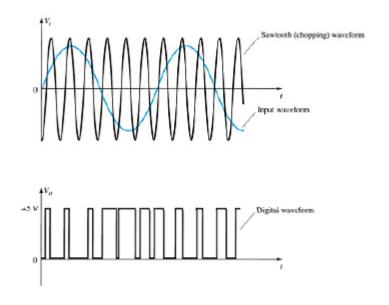
-a V_{out}

The power dissipation of the transistor in a class-C amplifier is low because it is on for only a small percentage of the input cycle. 11

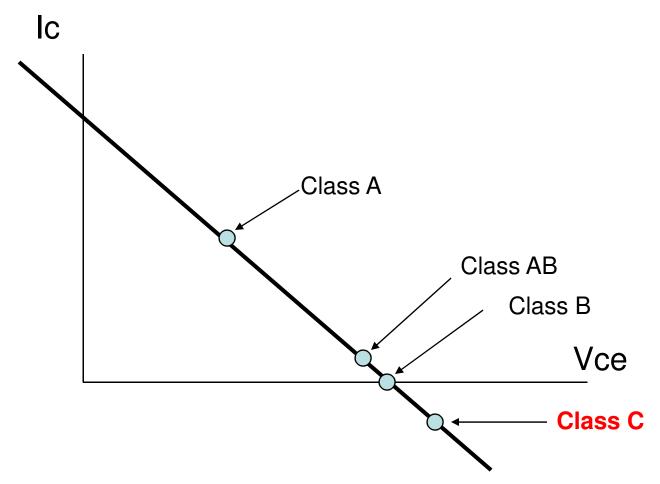
Class D power amplifier

A class D amplifier amplifies pulses, and requires a pulsed input.

There are many circuits that can convert a sinusoidal waveform to a pulse, as well as circuits that convert a pulse to a sine wave. This circuit has applications in digital circuitry.



Operating point on load line for various output stages



http://books.google.co.in/books?id=mrs1lwRTzo0C&pg=PR12&lpg=PR12&dq=frequency+response+of+multistage+ amplifiers&source=bl&ots=7vQ4XNKqom&sig=wsE3NpE8kja8FrqpKindgL_caNY&hl=en#v=onepage&q=frequency %20response%20of%20multistage%20amplifiers&f=false